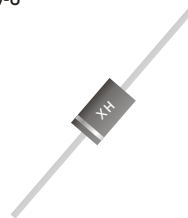


FEATURES

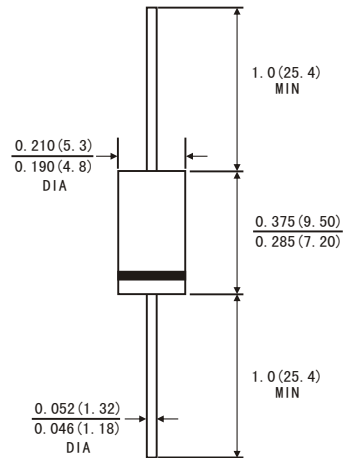
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260 C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

MECHANICAL DATA

- Case: JEDEC DO-201AD molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end
- Mounting Position: Any
- Weight: 0.041ounce, 1.15 grams



DO-201AD



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

	Symbols	SR 520L	SR 530L	SR 540L	SR 550L	SR 560L	SR 580L	SR 5100L	SR 5150L	SR 5200L	Units	
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	45	50	60	80	100	150	200	Volts	
Maximum RMS voltage	V _{RMS}	14	21	31	35	42	57	71	105	140	Volts	
Maximum DC blocking voltage	V _{DC}	20	30	45	50	60	80	100	150	200	Volts	
Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1)	I(AV)	5.0									Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated T _J)	I _{FSM}	150.0									Amps	
Maximum instantaneous forward voltage at 5.0 A(Note 1)	V _F	0.45			0.5		0.68		0.80	0.85	Volts	
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I _R	T _A = 25°C	0.5									mA
		T _A = 100°C	50			25						
Typical junction capacitance(Note 3)	C _J	500			400						pF	
Typical thermal resistance (Note 2)	R _{θJA}	25.0									°C/W	
	R _{θJL}	8.0										
Operating junction temperature range	T _J	-65 to +150									°C	
Storage temperature range	T _{STG}	-65 to +150									°C	

Notes: 1.Pulse test: 300μs pulse width,1% duty cycle

2.Thermal resistance from junction to lead vertical P.C.B. mounted , 0.375"(9.5mm)lead length

3.Measured at 1MHz and reverse voltage of 4.0 volts



RATINGS AND CHARACTERISTIC CURVES

FIG.1-FORWARD CURRENT DERATING CURVE

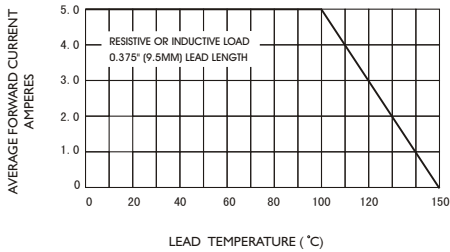


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

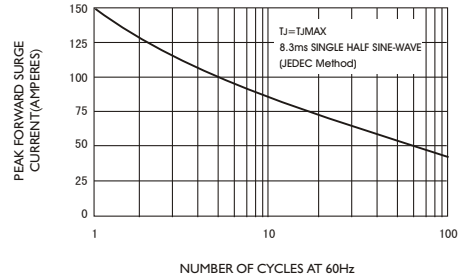


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

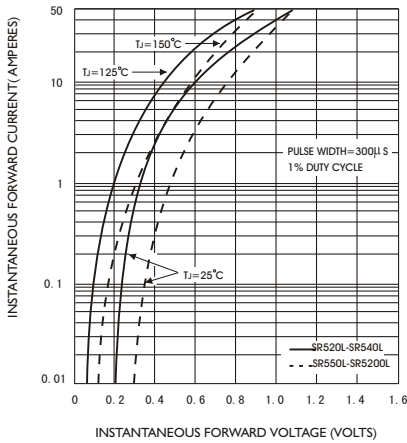


FIG.4-TYPICAL REVERSE CHARACTERISTICS

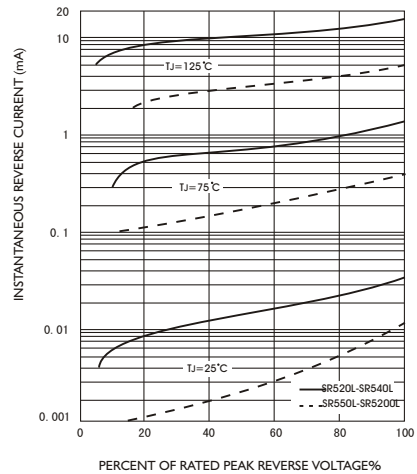


FIG.5-TYPICAL JUNCTION CAPACITANCE

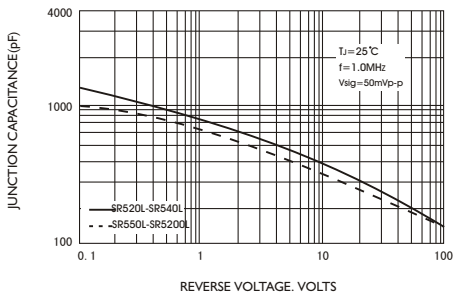


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

